

1.8V to 5.5V, 80 μ A, 8-, 10-, and 12-Bit, Low-Power, Single-Channel, DIGITAL-TO-ANALOG CONVERTERS in SC70 Package

FEATURES

- Relative Accuracy:
 - 0.25 LSB INL (DAC5311: 8-bit)
 - 0.5 LSB INL (DAC6311: 10-bit)
 - 1 LSB INL (DAC7311: 12-bit)
- *micro*Power Operation: 80µA at 1.8V
- Power-Down: 0.5μA at 5V, 0.1μA at 1.8V
- Wide Power Supply: +1.8V to +5.5V
- Power-On Reset to Zero Scale
- Straight Binary Data Format
- Low Power Serial Interface with Schmitt-Triggered Inputs: Up to 50MHz
- On-Chip Output Buffer Amplifier, Rail-to-Rail Operation
- SYNC Interrupt Facility
- Extended Temperature Range –40°C to +125°C
- Pin-Compatible Family in a Tiny, 6-Pin SC70 Package

APPLICATIONS

- Portable, Battery-Powered instruments
- Process Control
- Digital Gain and Offset Adjustment
- Programmable Voltage and Current Sources

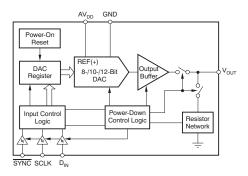
RELATED DEVICES	16-BIT	14-BIT	12-BIT	10-BIT	8-BIT
Pin and Function Compatible	DAC8411	DAC8311	DAC7311	DAC6311	DAC5311

DESCRIPTION

The DAC5311 (8-bit), DAC6311 (10-bit), and DAC7311 (12-bit) are low-power, single-channel, voltage output digital-to-analog converters (DAC). They are monotonic by design and provide excellent linearity and minimize undesired code-to-code transient voltages while offering an easy upgrade path within a pin-compatible family. All devices use a versatile, 3-wire serial interface that operates at clock rates of up to 50MHz and is compatible with standard SPI[™], QSPI[™], MICROWIRE[™], and digital signal processor (DSP) interfaces.

All devices use an external power supply as a reference voltage to set the output range. The devices incorporate a power-on reset (POR) circuit that ensures the DAC output powers up at 0V and remains there until a valid write to the device occurs. The DAC5311, DAC6311, and DAC7311 contain a power-down feature, accessed over the serial interface, that reduces current consumption of the device to 0.1μ A at 1.8V in power down mode. The low power consumption of this part in normal operation makes it ideally suited for portable, battery-operated equipment. The power consumption is 0.55mW at 5V, reducing to 2.5 μ W in power-down mode.

These devices are pin-compatible with the DAC8311 and DAC8411, offering an easy upgrade path from 8-, 10-, and 12-bit resolution to 14- and 16-bit. All devices are available in a small, 6-pin, SC70 package. This package offers a flexible, pin-compatible, and functionally-compatible drop-in solution within the family over an extended temperature range of -40°C to +125°C.



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DAC5311 DAC6311 DAC7311 SBAS442-AUGUST 2008



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This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PRODUCT	MAXIMUM RELATIVE ACCURACY (LSB)	MAXIMUM DIFFERENTIAL NONLINEARITY (LSB)	PACKAGE- LEAD	PACKAGE DESIGNATOR	SPECIFIED TEMPERATURE RANGE	PACKAGE MARKING
DAC5311	±0.25	±0.25	SC70-6	DCK	-40°C to 125°C	D53
DAC6311	±0.5	±0.5	SC70-6	DCK	-40°C to 125°C	D63
DAC7311	±1	±1	SC70-6	DCK	-40°C to 125°C	D73

PACKAGE/ORDERING INFORMATION⁽¹⁾

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

PARAMETER	VALUE	UNIT
AV _{DD} to GND	-0.3 to +6	V
Digital input voltage to GND	-0.3 to +AV _{DD} +0.3	V
AV _{OUT} to GND	-0.3 to +AV _{DD} +0.3	V
Operating temperature range	-40 to +125	°C
Storage temperature range	-65 to +150	°C
Junction temperature (T _J max)	+150	°C
Power dissipation	$(T_J max - T_A)/\theta_{JA}$	W
θ _{JA} thermal impedance	250	°C/W

(1) Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum conditions for extended periods may affect device reliability.



ELECTRICAL CHARACTERISTICS

At AV_{DD} = +1.8V to +5.5V, R_L = 2k\Omega to GND, and C_L = 200 pF to GND, unless otherwise noted.

				DAC5311, DAC6311, DAC7311				
F	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
STATIC PE	RFORMANCE ⁽¹⁾							
	Resolution		8			Bits		
DAC5311	Relative accuracy	Measured by the line passing through codes 3 and 252		±0.01	±0.25	LSB		
DACIOTI	Differential nonlinearity			±0.01	±0.25	LSB		
	Resolution		10			Bits		
DAC6311	Relative accuracy	Measured by the line passing through codes 12 and 1012		±0.06	±0.5	LSB		
DAGOSTI	Differential nonlinearity			±0.03	±0.5	LSB		
	Resolution		12			Bits		
DAC7311	Relative accuracy	Measured by the line passing through codes 30 and 4050		±0.3	±1	LSB		
DROTOTT	Differential nonlinearity			±0.2	±1	LSB		
Offset error		Measured by the line passing through two codes ⁽²⁾		±0.05	±4	mV		
Offset error	drift			3		μV/°C		
Zero code e	rror	All zeros loaded to the DAC register		0.2		mV		
Full-scale er	rror	All ones loaded to DAC register		0.04	0.2	% of FSR		
Gain error				0.05	±0.15	% of FSR		
<u> </u>		$AV_{DD} = +5V$		±0.5		ppm of		
Gain tempe	rature coefficient	$AV_{DD} = +1.8V$		±1.5		FSR/°C		
OUTPUT C	HARACTERISTICS ⁽³⁾							
Output volta	ge range		0		AV_{DD}	V		
	an nottling time	R_L = 2k\Omega, C_L = 200 pF, AV_{DD} = 5V, 1/4 scale to 3/4 scale		6	10	μs		
Output voita	ge settling time	$R_L = 2M\Omega, C_L = 470 pF$		12		μs		
Slew rate				0.7		V/µs		
Capacitive le	and atability	R _L = ∞		470		pF		
	Dad Stability	$R_L = 2k\Omega$		1000		pF		
Code chang	e glitch impulse	1LSB change around major carry		0.5		nV-s		
Digital feedt	hrough			0.5		nV-s		
Power-on gl	itch impulse	$R_L = 2k\Omega$, $C_L = 200pF$, $AV_{DD} = 5V$		17		mV		
DC output in	mpedance			0.5		Ω		
Short-circuit	current	$AV_{DD} = +5V$		50		mA		
Short-circuit	current	$AV_{DD} = +3V$		20		mA		
Power-up tir	me	Coming out of power-down mode		50		μs		
AC PERFO	RMANCE							
SNR				81		dB		
THD		T_A = +25°C, BW = 20kHz, 12-bit level, AV _{DD} = 5V, f _{OUT} = 1kHz, 1st 19 harmonics removed for SNR		-65		dB		
SFDR		calculation		65		dB		
SINAD				65		dB		
	noine density (4)	T_A = +25°C, at zero-scale input, f_{OUT} = 1kHz, AV _{DD} = 5V		17		nV/√ Hz		
	noise density ⁽⁴⁾	T_A = +25°C, at mid-code input, f_{OUT} = 1kHz, AV _{DD} = 5V		110		nV/√Hz		
DAC output	noise ⁽⁵⁾	T_A = +25°C, at mid-code input, 0.1Hz to 10Hz, AV _{DD} = 5V		3		μV _{PP}		

(1) Linearity calculated using a reduced code range of 3 to 252 for 8-bit, 12 to 1012 for 10bit, and 30 to 4050 for 12-bit, output unloaded.

Straight line passing through codes 3 and 252 for 8-bit, 12 and 1012 for 10bit, and 30 and 4050 for 12-bit, output unloaded. Specified by design and characterization, not production tested. (2)

(3)

For more details, see Figure 22. (4)

For more details, see Figure 23. (5)

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ELECTRICAL CHARACTERISTICS (continued)

At AV_{DD} = +1.8V to +5.5V, R_L = 2k\Omega to GND, and C_L = 200 pF to GND, unless otherwise noted.

					11, DAC6 AC7311	311,		
I	PARAMETER	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT	
LOGIC INP	UTS ⁽⁶⁾							
Input currer	nt					±1	μA	
V _{IN} L, input low voltage		$AV_{DD} = +5V$				0.8	V	
v _{IN} ∟, input	ow vollage	$AV_{DD} = +1.8V$			0.5	V		
V II input	high voltage	$AV_{DD} = +5V$		1.8			V	
V _{IN} H, input high voltage		AV _{DD} = +1.8V	1.1			V		
Pin capacita	ance			1.5 3		pF		
POWER RE	QUIREMENTS							
AV _{DD}				1.8		5.5	V	
	Normal mode		$AV_{DD} = 3.6V$ to $5.5V$		110	160		
		$V_{IN}H = AV_{DD}$ and $V_{IN}L =$ GND, at midscale code ⁽⁷⁾	AV _{DD} = 2.7V to 3.6V		95	150	μA	
			$AV_{DD} = 1.8V$ to 2.7V		80	140		
I _{DD}			$AV_{DD} = 3.6V$ to $5.5V$		0.5	3.5		
	All power-down mode	V _{IN} H = AV _{DD} and V _{IN} L = GND, at midscale code	AV _{DD} = 2.7V to 3.6V		0.4	3.0	μA	
			$AV_{DD} = 1.8V$ to 2.7V		0.1	0.8 0.5 3 3 5.5 160 150 140 3.5 3.0 2.0 0.88 0.54 0.38 19.2 10.8 8.1		
			$AV_{DD} = 3.6V$ to $5.5V$		0.55	0.88		
	Normal mode	V _{IN} H = AV _{DD} and V _{IN} L = GND, at midscale code	$AV_{DD} = 2.7V$ to $3.6V$		0.25	0.54	mW	
Power			AV_{DD} = 1.8V to 2.7V		0.14	0.38		
dissipation			$AV_{DD} = 3.6V$ to $5.5V$		2.50	19.2		
	All power-down mode	V _{IN} H = AV _{DD} and V _{IN} L = GND, at midscale code	$AV_{DD} = 2.7V$ to $3.6V$		1.08	10.8	μW	
		Grad, at miuscale code	AV_{DD} = 1.8V to 2.7V		0.72	8.1		
TEMPERA				•				
Specified p	erformance range			-40		+125	°C	

(6) Specified by design and characterization, not production tested.

(7) For more details, see Figure 15, Figure 58, and Figure 91.



PIN CONFIGURATION

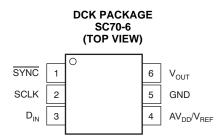


Table 1. PIN DESCRIPTION

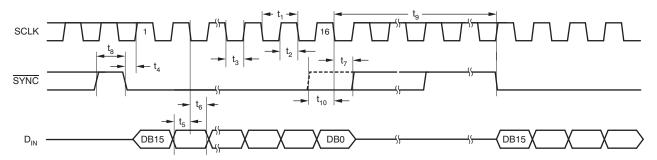
PIN	NAME	DESCRIPTION
1	SYNC	Level-triggered control input (active low). This is the frame sychronization signal for the input data. When SYNC goes low, it enables the input shift register and data are transferred in on the falling edges of the following clocks. The DAC is updated following 16th clock cycle, unless SYNC is taken high before this edge, in which case the rising edge of SYNC acts as an interrupt and the write sequence is ignored by the DACx311. Refer to the SYNC Interrupt section for more details.
2	SCLK	Serial Clock Input. Data can be transferred at rates up to 50MHz.
3	D _{IN}	Serial Data Input. Data is clocked into the 16-bit input shift register on the falling edge of the serial clock input.
4	AV _{DD} /V _{REF}	Power Supply Input, +1.8V to 5.5V.
5	GND	Ground reference point for all circuitry on the part.
6	V _{OUT}	Analog output voltage from DAC. The output amplifier has rail-to-rail operation.

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SERIAL WRITE OPERATION



TIMING REQUIREMENTS⁽¹⁾

All specifications at -40°C to +125°C, and AV_{DD} = +1.8V to +5.5V, unless otherwise noted.

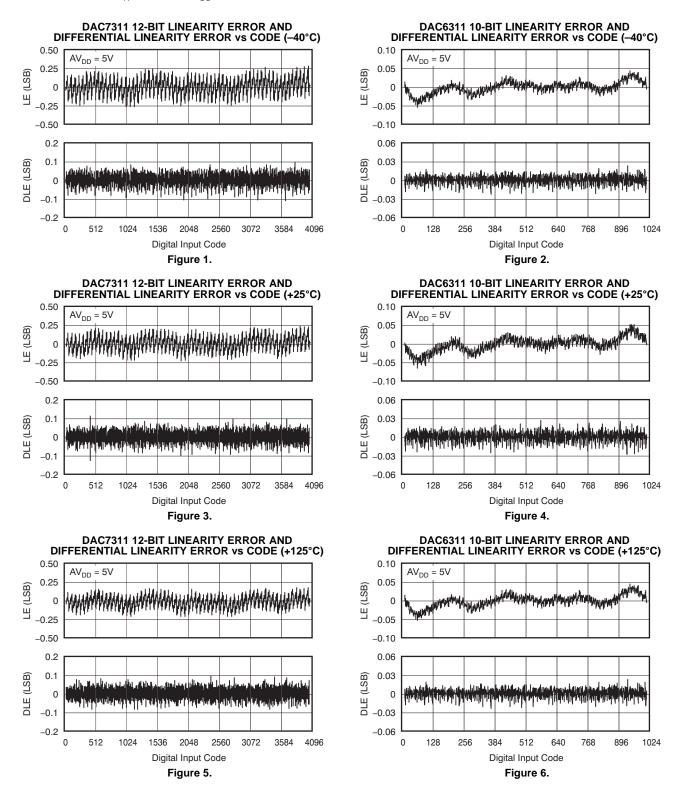
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t ₁ ⁽²⁾		AV _{DD} = 1.8V to 3.6V	50			
ι ₁ ,	SCLK cycle time	AV _{DD} = 3.6V to 5.5V	20			ns
	COLIC high time	AV _{DD} = 1.8V to 3.6V	25			20
t ₂	SCLK high time	$AV_{DD} = 3.6V \text{ to } 5.5V$	10			ns
		AV _{DD} = 1.8V to 3.6V	25			20
t ₃	SCLK low time	AV _{DD} = 3.6V to 5.5V	10			ns
	<u>EVNIC</u> to SCLK rising adaptation time	AV _{DD} = 1.8V to 3.6V	0			~~
t ₄	SYNC to SCLK rising edge setup time	AV _{DD} = 3.6V to 5.5V	0			ns
	Data actum time	AV _{DD} = 1.8V to 3.6V	5			
t5	Data setup time	AV _{DD} = 3.6V to 5.5V	5			ns
	Data hald time	AV _{DD} = 1.8V to 3.6V	4.5			20
t ₆	Data hold time	AV _{DD} = 3.6V to 5.5V	4.5			ns
	CCLIC falling adapts 5 SVNC vising adap	AV _{DD} = 1.8V to 3.6V			20	
t ₇	SCLK falling edge to SYNC rising edge	AV _{DD} = 3.6V to 5.5V	0			ns
		AV _{DD} = 1.8V to 3.6V	50			
t ₈	Minimum SYNC high time	AV _{DD} = 3.6V to 5.5V	20			ns
	16th COLIX folling added to CVNC folling added	AV _{DD} = 1.8V to 3.6V	100			~~
tg	16th SCLK falling edge to SYNC falling edge	$AV_{DD} = 3.6V \text{ to } 5.5V$ 100				ns
	SYNC rising edge to 16th SCLK falling edge	SCLK falling edge AV _{DD} = 1.8V to 3.6V 15				
t ₁₀	(for successful SYNC interrupt)	AV _{DD} = 3.6V to 5.5V	15			ns

All input signals are specified with $t_R = t_F = 3ns (10\% \text{ to } 90\% \text{ of } AV_{DD})$ and timed from a voltage level of $(V_{IL} + V_{IH})/2$. Maximum SCLK frequency is 50MHz at $AV_{DD} = 3.6V$ to 5.5V and 20MHz at $AV_{DD} = 1.8V$ to 3.6V. (1)

(2)

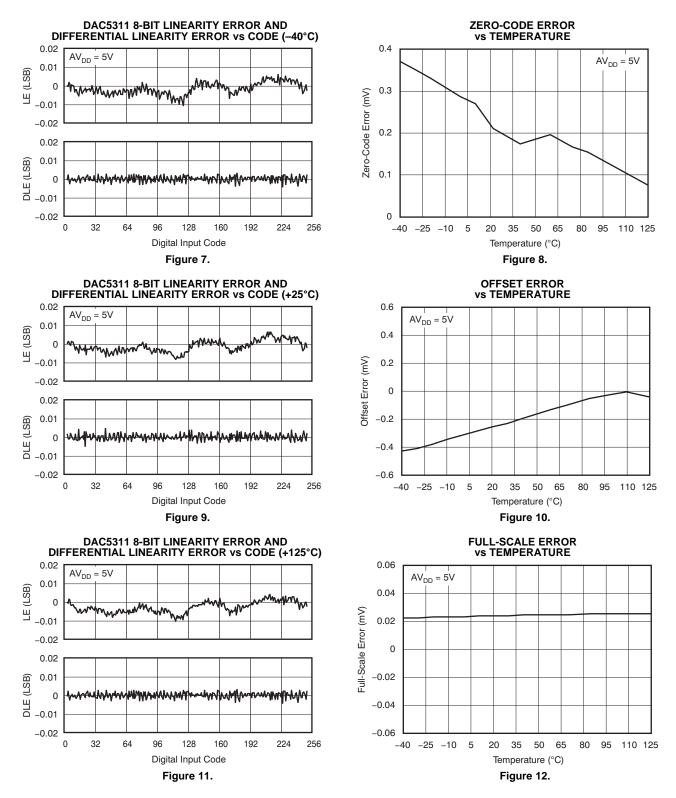








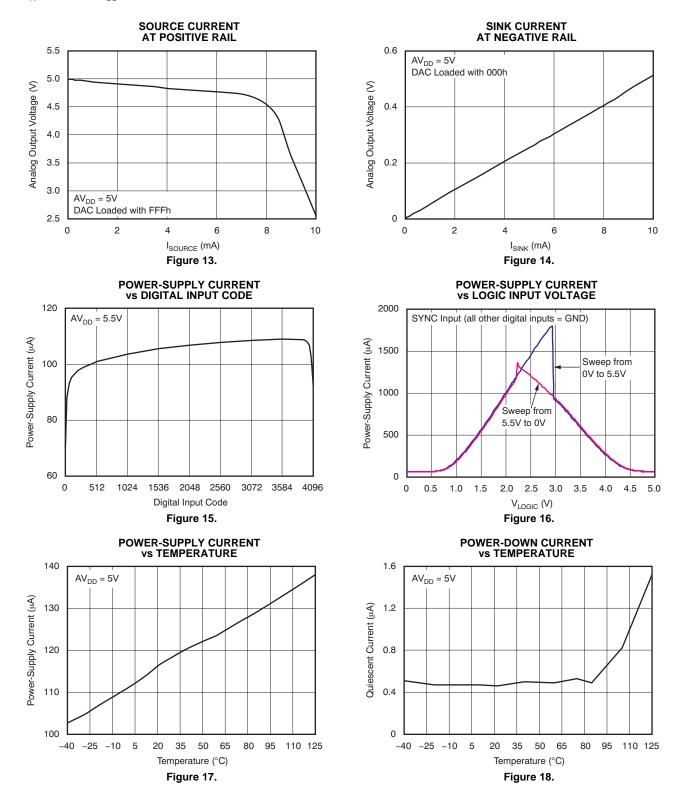
TYPICAL CHARACTERISTICS: AV_{DD} = +5V (continued)





TYPICAL CHARACTERISTICS: AV_{DD} = +5V (continued)

At $T_A = +25^{\circ}C$, $AV_{DD} = +5V$, and DAC loaded with midscale code, unless otherwise noted.



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TYPICAL CHARACTERISTICS: AV_{DD} = +5V (continued)

At $T_A = +25^{\circ}C$, $AV_{DD} = +5V$, and DAC loaded with midscale code, unless otherwise noted.

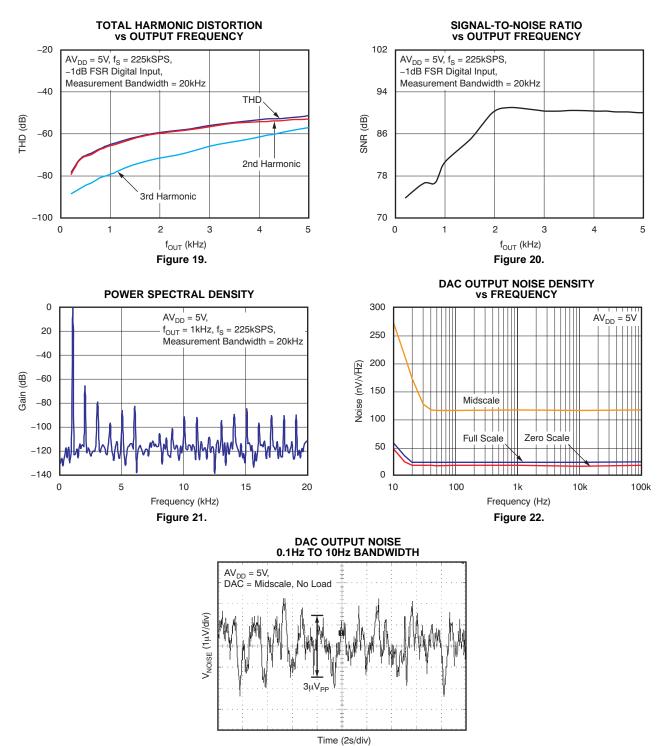


Figure 23.



TYPICAL CHARACTERISTICS: AV_{DD} = +5V (continued)

At $T_A = +25^{\circ}C$, $AV_{DD} = +5V$, and DAC loaded with midscale code, unless otherwise noted.

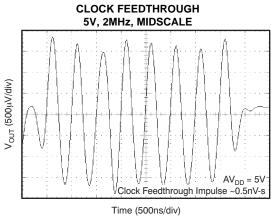
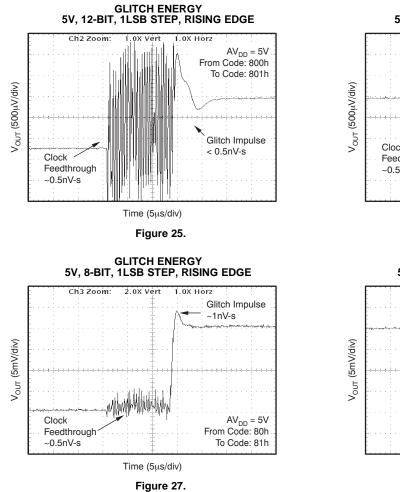


Figure 24.



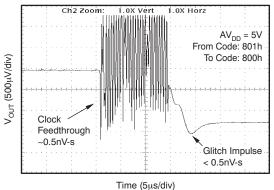
GLITCH ENERGY 5V, 12-BIT, 1LSB STEP, FALLING EDGE

DAC5311

DAC6311

DAC7311

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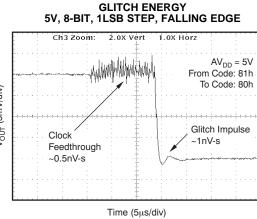


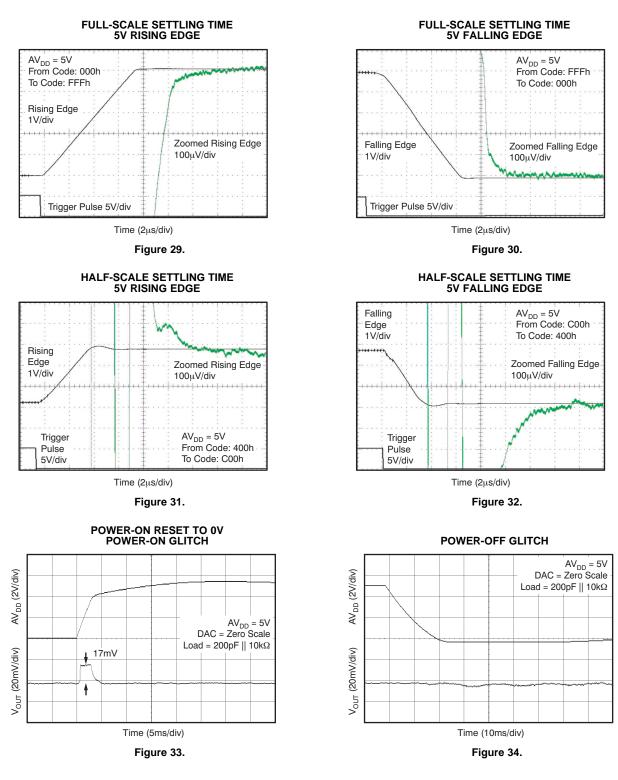
Figure 28.

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TYPICAL CHARACTERISTICS: AV_{DD} = +5V (continued)

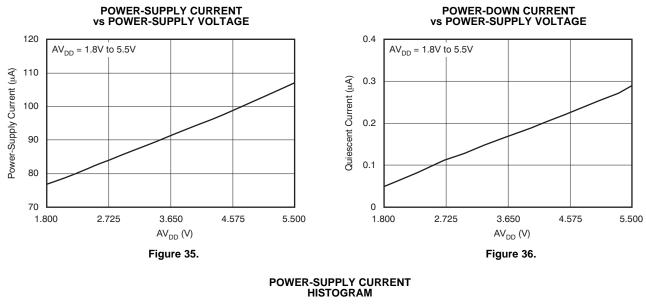
At $T_A = +25^{\circ}C$, $AV_{DD} = +5V$, and DAC loaded with midscale code, unless otherwise noted.

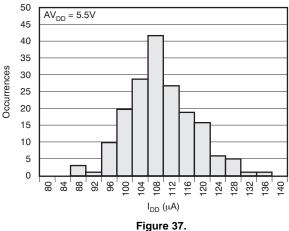


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TYPICAL CHARACTERISTICS: AV_{DD} = +5V (continued)

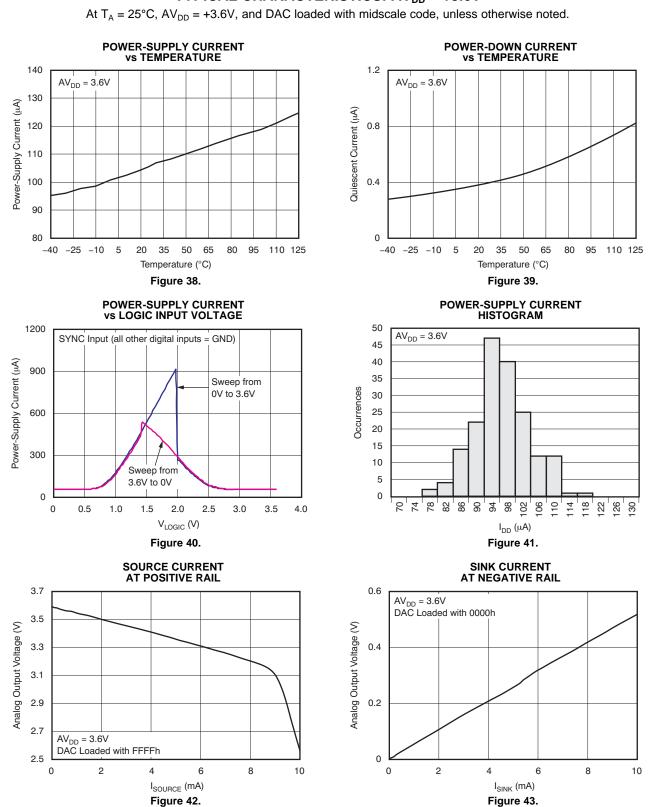




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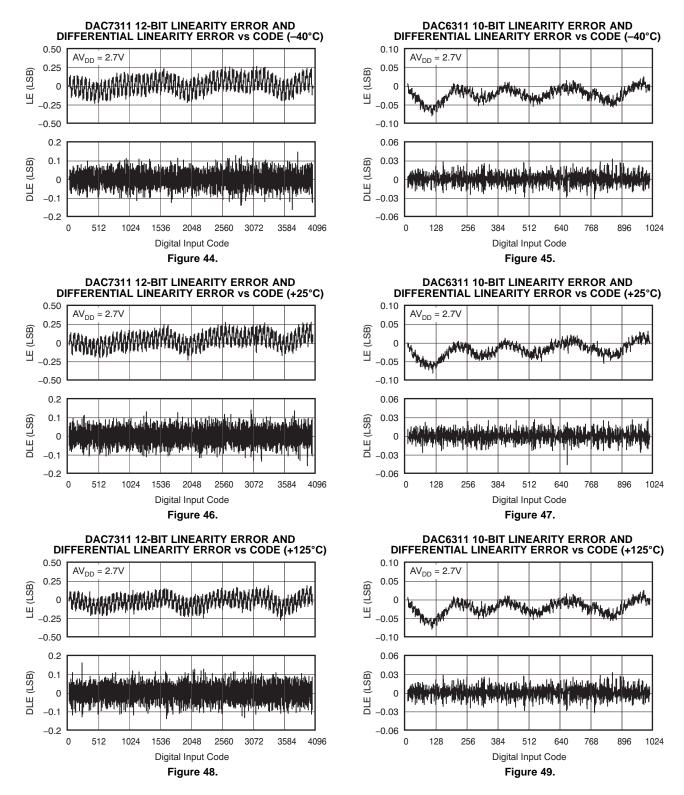
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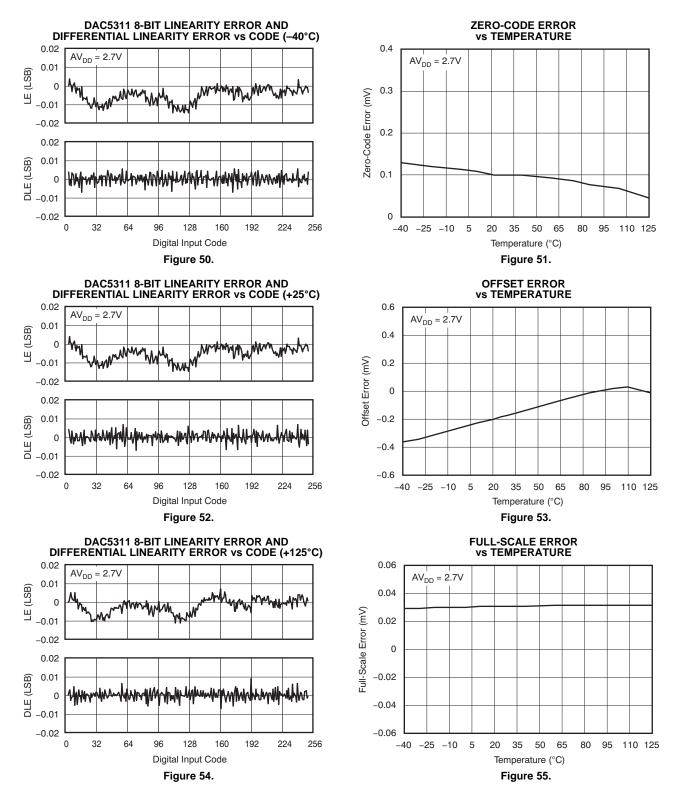






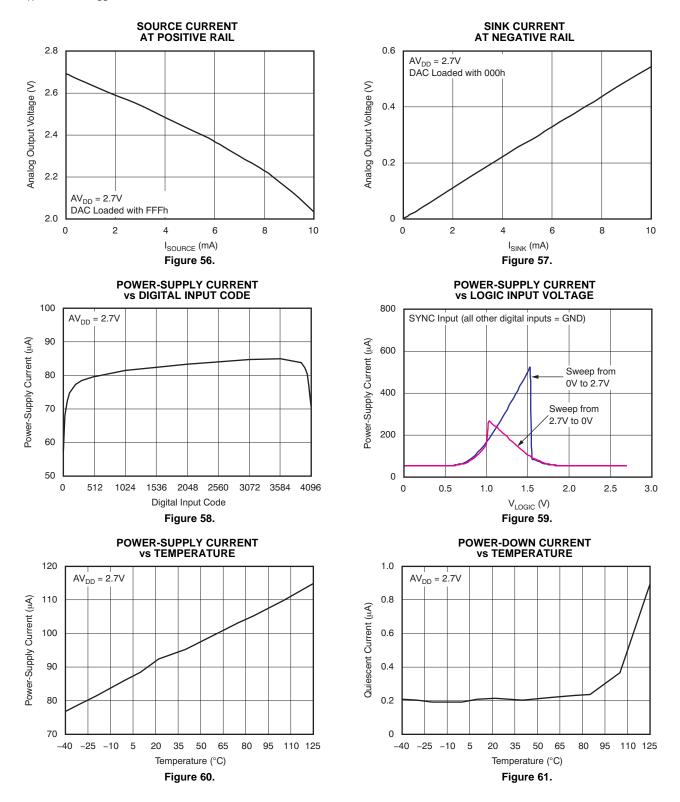


TYPICAL CHARACTERISTICS: AV_{DD} = +2.7V (continued)





TYPICAL CHARACTERISTICS: AV_{DD} = +2.7V (continued)





TYPICAL CHARACTERISTICS: AV_{DD} = +2.7V (continued)

At $T_A = 25^{\circ}$ C, $AV_{DD} = +2.7$ V, and DAC loaded with midscale code, unless otherwise noted.

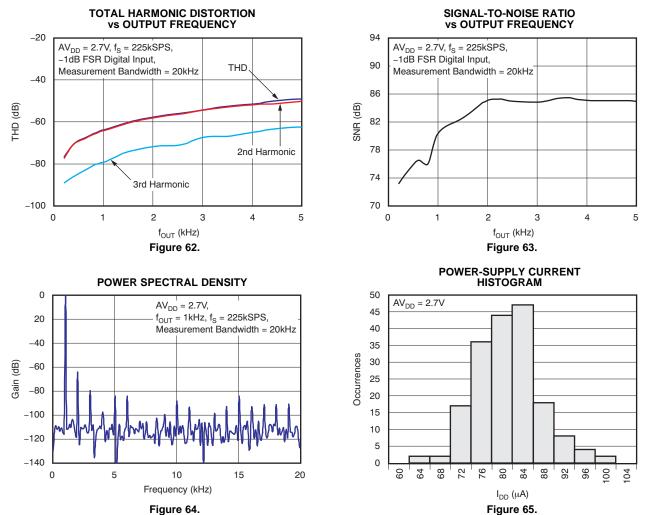


Figure 64.

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TYPICAL CHARACTERISTICS: AV_{DD} = +2.7V (continued)

At $T_A = 25^{\circ}$ C, $AV_{DD} = +2.7$ V, and DAC loaded with midscale code, unless otherwise noted.

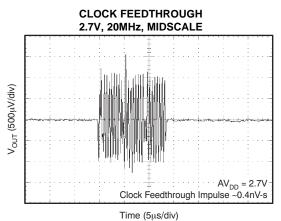
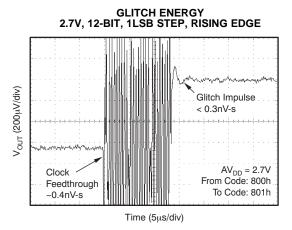
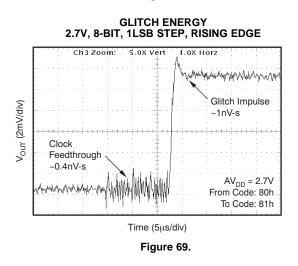


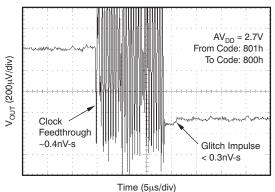
Figure 66.



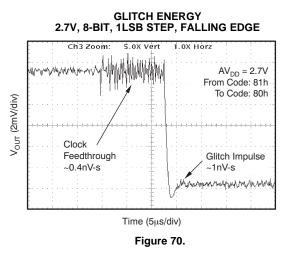




GLITCH ENERGY 2.7V, 12-BIT, 1LSB STEP, FALLING EDGE







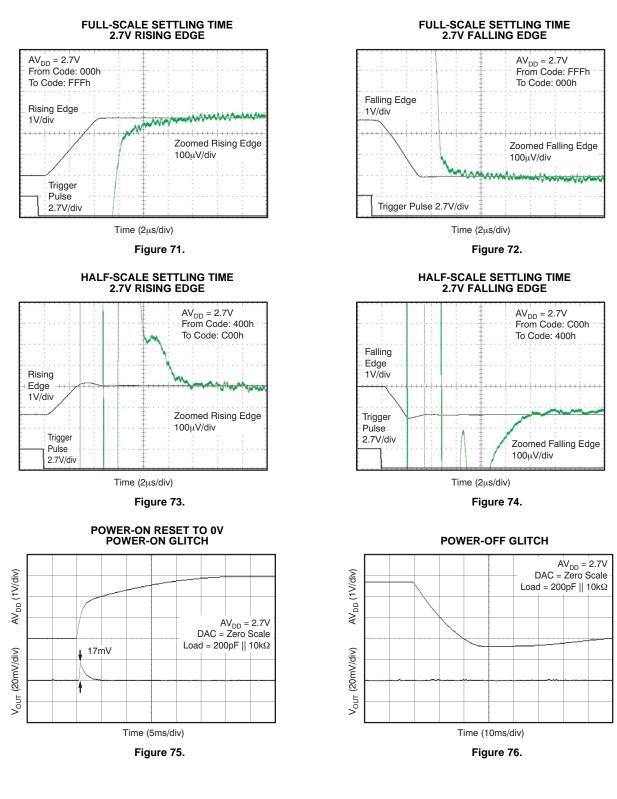
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TYPICAL CHARACTERISTICS: AV_{DD} = +2.7V (continued)

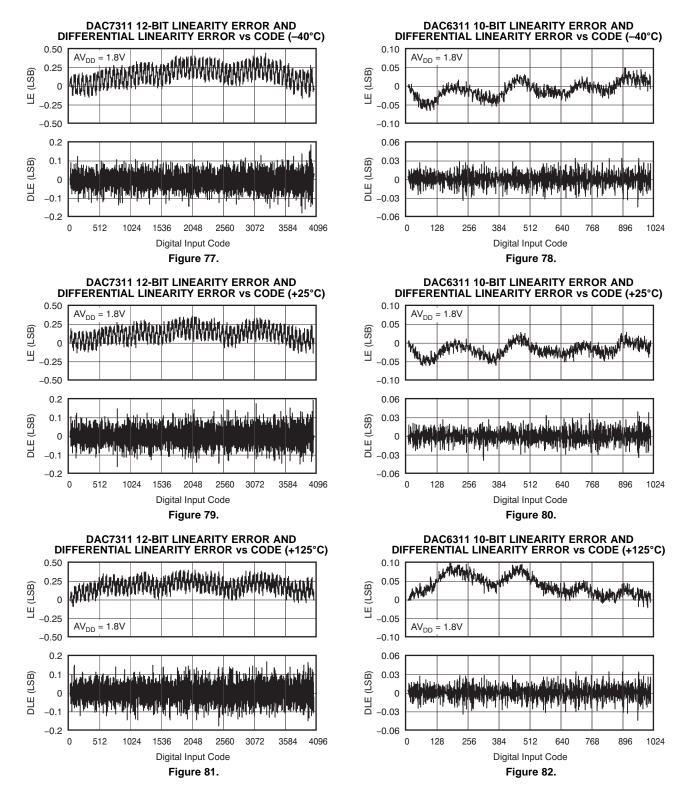
At $T_A = 25^{\circ}$ C, $AV_{DD} = +2.7$ V, and DAC loaded with midscale code, unless otherwise noted.



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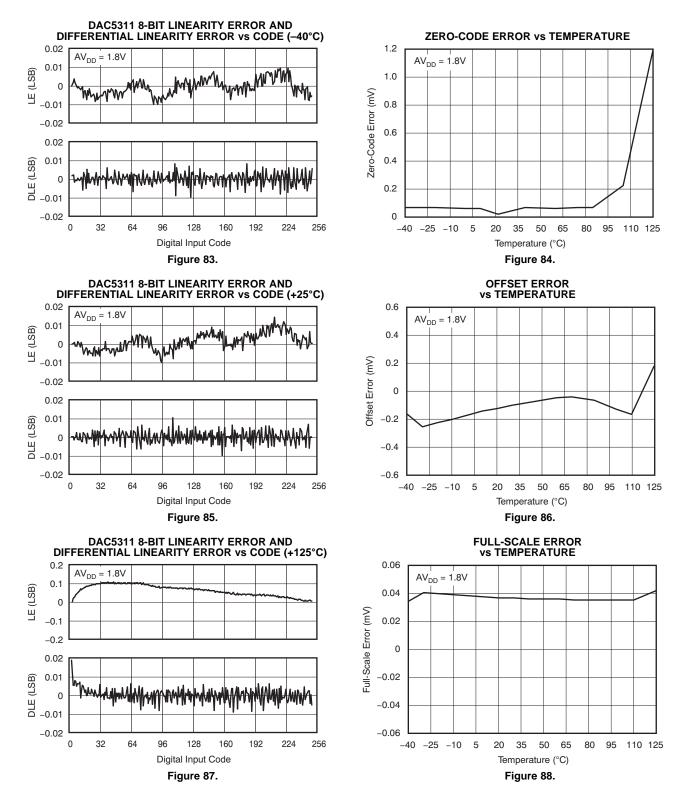






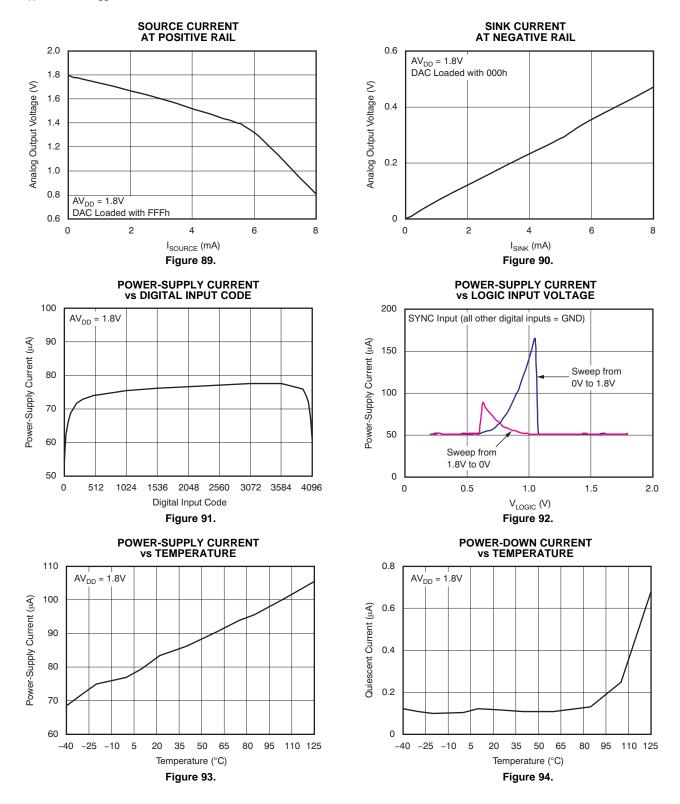


TYPICAL CHARACTERISTICS: AV_{DD} = +1.8V (continued)





TYPICAL CHARACTERISTICS: AV_{DD} = +1.8V (continued)





TYPICAL CHARACTERISTICS: AV_{DD} = +1.8V (continued)

At $T_A = 25^{\circ}$ C, $AV_{DD} = +1.8$ V, and DAC loaded with midscale code, unless otherwise noted.

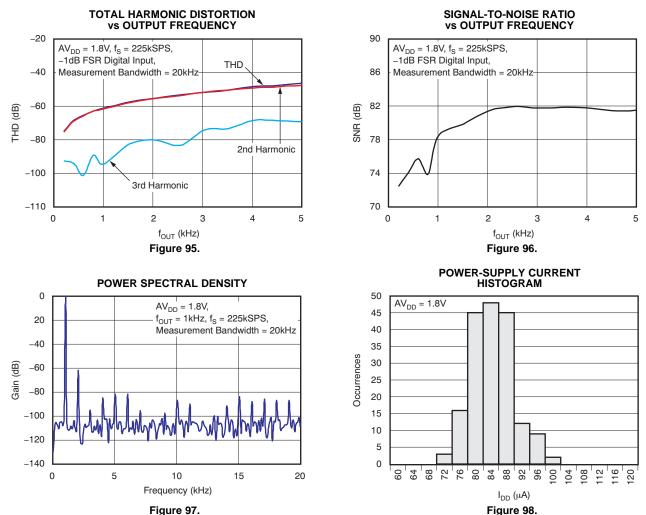


Figure 97.

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TYPICAL CHARACTERISTICS: AV_{DD} = +1.8V (continued)

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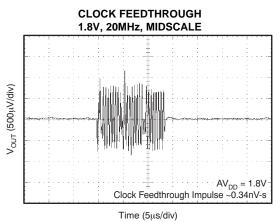


Figure 99.

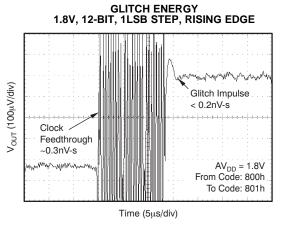
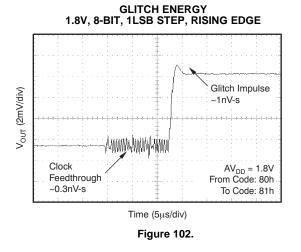


Figure 100.



GLITCH ENERGY 1.8V, 12-BIT, 1LSB STEP, FALLING EDGE

DAC5311

DAC6311

DAC7311

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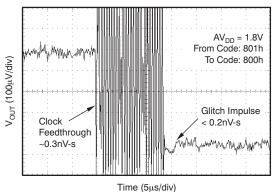
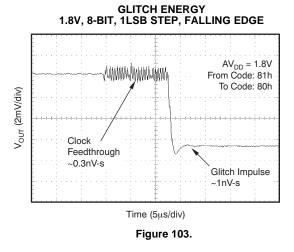


Figure 101.

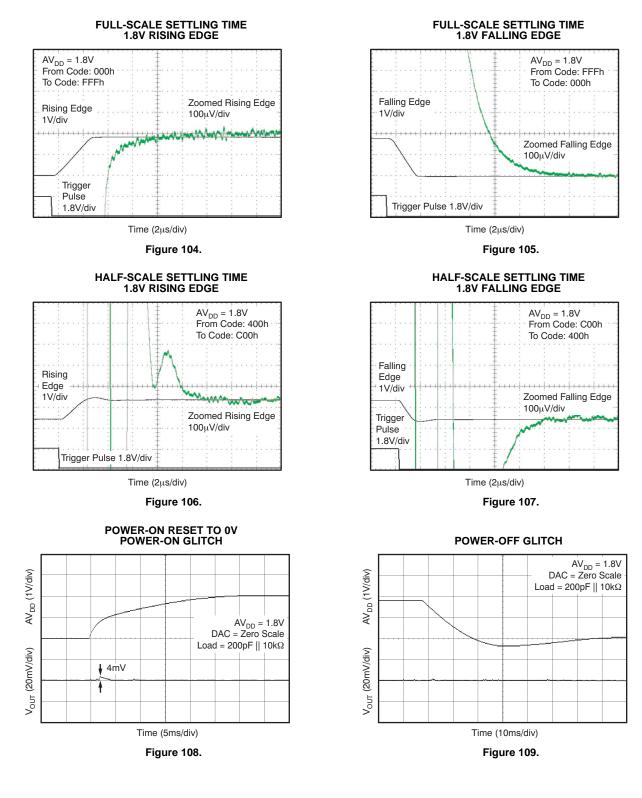


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TYPICAL CHARACTERISTICS: AV_{DD} = +1.8V (continued)





THEORY OF OPERATION

DAC SECTION

The DAC5311, DAC6311, and DAC7311 are fabricated using TI's proprietary HPA07 process technology. The architecture consists of a string DAC followed by an output buffer amplifier. Because there is no reference input pin, the power supply (AV_{DD}) acts as the reference. Figure 110 shows a block diagram of the DAC architecture.

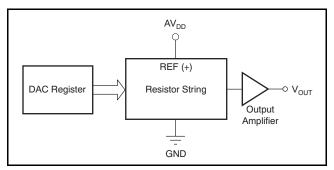


Figure 110. DACx311 Architecture

The input coding to the DACx311 is straight binary, so the ideal output voltage is given by:

$$V_{OUT} = AV_{DD} \times \frac{D}{2^n}$$

Where:

n = resolution in bits; either 8 (DAC5311), 10 (DAC6311), or 12 (DAC7311).

D = decimal equivalent of the binary code that is loaded to the DAC register. It ranges from 0 to 255 for 8-bit DAC5311; from 0 to 1023 for the 10-bit DAC6311; and 0 to 4095 for the 12-bit DAC7311.

RESISTOR STRING

The resistor string section is shown in Figure 111. It is simply a string of resistors, each of value R. The code loaded into the DAC register determines at which node on the string the voltage is tapped off to be fed into the output amplifier by closing one of the switches connecting the string to the amplifier. It is tested monotonic because it is a string of resistors.

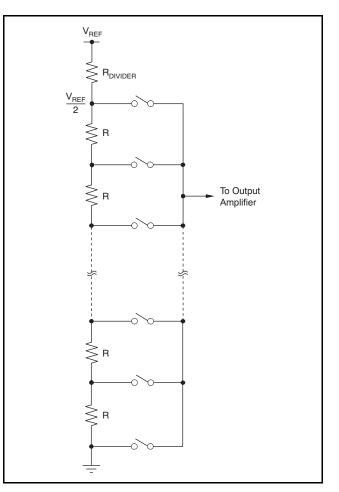


Figure 111. Resistor String

OUTPUT AMPLIFIER

The output buffer amplifier is capable of generating rail-to-rail voltages on its output which gives an output range of 0V to AV_{DD}. It is capable of driving a load of $2k\Omega$ in parallel with 1000pF to GND. The source and sink capabilities of the output amplifier can be seen in the Typical Characteristics section for the given voltage input. The slew rate is 0.7V/µs with a half-scale settling time of typically 6µs with the output unloaded.



SERIAL INTERFACE

The DACx311 has a 3-wire serial interface (SYNC, SCLK, and DIN) compatible with SPI, QSPI, and Microwire interface standards, as well as most DSPs. See the Serial Write Operation timing diagram for an example of a typical write sequence.

DACx311 Input Shift Register

The input shift register is 16 bits wide, as shown in Table 2. The first two bits (PD0 and PD1) are reserved control bits that set the desired mode of operation (normal mode or any one of three power-down modes) as indicated in Table 5.

The remaining data bits are either 12 (DAC7311), 10 (DAC6311), or 8 (DAC5311) data bits, followed by *don't care* bits, as shown in Table 2, Table 3, and Table 4, respectively.

The write sequence begins by bringing the \overline{SYNC} line low. Data from the DIN line are clocked into the 16-bit shift register on each falling edge of SCLK. The serial clock frequency can be as high as 50MHz, making the DACx311 compatible with high-speed DSPs. On the 16th falling edge of the serial clock, the last data bit is clocked in and the programmed function is executed.

At this point, the SYNC line may be kept low or brought high. In either case, it must be brought high for a minimum of 20ns before the next write sequence so that a falling edge of SYNC can initiate the next write sequence. As previously mentioned, it must be brought high again before the next write sequence.

DACx311 SYNC Interrupt

In a normal write sequence, the SYNC line is kept low for at least 16 falling edges of SCLK and the DAC is updated on the 16th falling edge. However, bringing SYNC high before the 16th falling edge acts as an interrupt to the write sequence. The shift register is reset and the write sequence is seen as invalid. Neither an update of the DAC register contents nor a change in the operating mode occurs, as shown in Figure 112.

	Table 2. DAC5311 8-Bit Data Input Register														
DB15	DB14								DB6	DB5					DB0
PD1	PD0	D7	D6	D5	D4	D3	D2	D1	D0	Х	Х	Х	Х	Х	Х
	Table 2. DAOCO44 40 Bit Date Innut Daviator														
Table 3. DAC6311 10-Bit Data Input Register															
DB15	DB14										DB4	DB3			DB0
PD1	PD0	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0	Х	Х	Х	Х
					Table	4. DA	C7311	12-Bit	Data In	put Reg	gister				
DB15	DB14												DB2	DB1	DB0
PD1	PD0	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0	Х	Х
							"							((
CLK		UU			лл		דשר							$\square \square$	UL
SYNC	$-\tau$	7								_					
01110		<u> </u>								<u> </u>			_		
D _{IN}															
	Invalid Write Sequence: Valid Write Sequence:														
		SYNC HI	GH before	e 16th Fa	lling Edge)				Output U	pdates on 1	6th Falling	Edge		

Figure 112. DACx311 SYNC Interrupt Facility



POWER-ON RESET TO ZERO-SCALE

The DACx311 contains a power-on reset circuit that controls the output voltage during power-up. On power-up, the DAC register is filled with zeros and the output voltage is 0V. The DAC register remains that way until a valid write sequence is made to the DAC. This design is useful in applications where it is important to know the state of the output of the DAC while it is in the process of powering up.

The occurring power-on glitch impulse is only a few millivolts (typically, 17mV; see Figure 33).

POWER-DOWN MODES

The DACx311 contains four separate modes of operation. These modes are programmable by setting two bits (PD1 and PD0) in the control register. Table 5 shows how the state of the bits corresponds to the mode of operation of the device.

Table 5. Modes of Operation for the DACx311

PD1	PD0	OPERATING MODE						
Normal	Mode							
0	0	Normal Operation						
Power-	Power-Down Modes							
0	1	Output 1kΩ to GND						
1	0	Output 100kΩ to GND						
1	1	High-Z						

When both bits are set to '0', the device works normally with a standard power consumption of typically 80μ A at 1.8V. However, for the three power-down modes, the typical supply current falls to 0.5 μ A at 5V, 0.4 μ A at 3V, and 0.1 μ A at 1.8V. Not only does the supply current fall, but the output stage

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is also internally switched from the output of the amplifier to a resistor network of known values. The advantage of this architecture is that the output impedance of the part is known while the part is in power-down mode. There are three different options. The output is connected internally to GND either through a $1k\Omega$ resistor or a $100k\Omega$ resistor, or is left open-circuited (High-Z). Figure 113 illustrates the output stage.

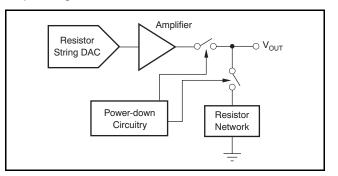


Figure 113. Output Stage During Power-Down

All linear circuitry is shut down when the power-down mode is activated. However, the contents of the DAC register are unaffected when in power-down. The time to exit power-down is typically $50\mu s$ for $AV_{DD} = 5V$ and $AV_{DD} = 3V$.

DAC NOISE PERFORMANCE

Typical noise performance for the DACx311 is shown in Figure 34 and 35. Output noise spectral density at the V_{OUT} pin versus frequency is depicted in Figure 34 for full-scale, midscale, and zero-scale input codes. The typical noise density for midscale code is $110nV/\sqrt{Hz}$ at 1kHz and at 1MHz.

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APPLICATION INFORMATION

USING THE REF5050 AS A POWER SUPPLY FOR THE DACx311

As a result of the extremely low supply current required by the DACx311, an alternative option is to use a REF5050 +5V precision voltage reference to supply the required voltage to the part, as shown in Figure 114. This option is especially useful if the power supply is too noisy or if the system supply voltages are at some value other than 5V. The REF5050 outputs a steady supply voltage for the DACx311. If the REF5050 is used, the current needed to supply DACx311 is typically 110µA at 5V, with no load on the output of the DAC. When the DAC output is loaded, the REF5050 also needs to supply the current to the load. The total current required (with a 5k Ω load on the DAC output) is:

 $110\mu A + (5V/5k\Omega) = 1.11mA$

The load regulation of the REF5050 is typically 0.002%/mA, which results in an error of 90μ V for the 1.1mA current drawn from it. This value corresponds to a 0.07LSB error at 12 bits (DAC7311).

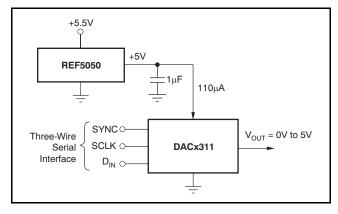


Figure 114. REF5050 as Power Supply to DACx311

For other power-supply voltages, alternative references such as the REF3030 (3V), REF3033 (3.3V), or REF3220 (2.048V) are recommended. For a full list of available voltage references from TI, see the TI web site at www.ti.com.

BIPOLAR OPERATION USING THE DACx311

The DACx311 has been designed for single-supply operation but a bipolar output range is also possible using the circuit in Figure 115. The circuit shown gives an output voltage range of \pm 5V. Rail-to-rail operation at the amplifier output is achievable using an OPA211, OPA340, or OPA703 as the output amplifier. For a full list of available operational amplifiers from TI, see the TI web site at www.ti.com

The output voltage for any input code can be calculated as follows:

$$V_{O} = \left[AV_{DD} \times \left(\frac{D}{2^{n}}\right) \times \left(\frac{R_{1} + R_{2}}{R_{1}}\right) - AV_{DD} \times \left(\frac{R_{2}}{R_{1}}\right) \right]$$
(1)

Where:

n = resolution in bits; either 8 (DAC5311), 10 (DAC6311), or 12 (DAC7311).

D = decimal equivalent of the binary code that is loaded to the DAC register. It ranges from 0 to 255 for 8-bit DAC5311; from 0 to 1023 for the 10-bit DAC6311; and 0 to 4095 for the 12-bit DAC7311.

With
$$AV_{DD} = 5V$$
, $R_1 = R_2 = 10k\Omega$:

$$V_{O} = \left(\frac{10 \times D}{2^{n}}\right) - 5V \tag{2}$$

This is an output voltage range of $\pm 5V$ with 000h (12-bit level) corresponding to a -5V output and FFFh (12-bit level) corresponding to a $\pm 5V$ output.

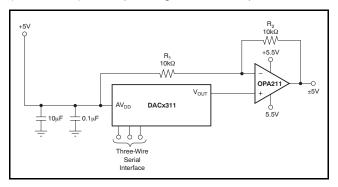


Figure 115. Bipolar Operation with the DACx311



MICROPROCESSOR INTERFACING

DACx311 to 8051 Interface

Figure 116 shows a serial interface between the DACx311 and a typical 8051-type microcontroller. The setup for the interface is as follows: TXD of the 8051 drives SCLK of the DACx311, while RXD drives the serial data line of the part. The SYNC signal is derived from a bit programmable pin on the port. In this case, port line P3.3 is used. When data are to be transmitted to the DACx311, P3.3 is taken low. The 8051 transmits data only in 8-bit bytes; thus, only eight falling clock edges occur in the transmit cycle. To load data to the DAC, P3.3 remains low after the first eight bits are transmitted, and a second write cycle is initiated to transmit the second byte of data. P3.3 is taken high following the completion of this cycle. The 8051 outputs the serial data in a format which has the LSB first. The DACx311 requires its data with the MSB as the first bit received. Therefore, the 8051 transmit routine must take this requirement into account, and *mirror* the data as needed.

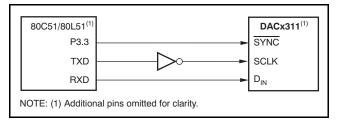
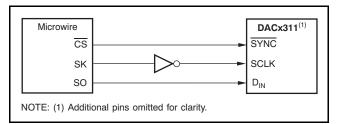


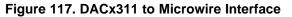
Figure 116. DACx311 to 80C51/80L51 Interfaces

DACx311 to Microwire Interface

Figure 117 shows an interface between the DACx311 and any Microwire-compatible device. Serial data are shifted out on the falling edge of the serial clock and are clocked into the DACx311 on the rising edge of the SK signal.







DACx311 to 68HC11 Interface

Figure 118 shows a serial interface between the DACx311 and the 68HC11 microcontroller. SCK of the 68HC11 drives the SCLK of the DACx311, while the MOSI <u>output</u> drives the serial data line of the DAC. The SYNC signal is derived from a port line (PC7), similar to what was done for the 8051.

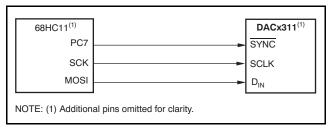


Figure 118. DACx311 to 68HC11 Interface

The 68HC11 should be configured so that its CPOL bit is a '0' and its CPHA bit is a '1'. This configuration causes data appearing on the MOSI output to be valid on the falling edge of SCK. When data are being transmitted to the DAC, the SYNC line is taken low (PC7). Serial data from the 68HC11 are transmitted in 8-bit bytes with only eight falling clock edges occurring in the transmit cycle. Data are transmitted MSB first. In order to load data to the DACx311, PC7 is held low after the first eight bits are transferred, and a second serial write operation is performed to the DAC; PC7 is taken high at the end of this procedure.



LAYOUT

A precision analog component requires careful layout, adequate bypassing, and clean, well-regulated power supplies.

The DACx311 offers single-supply operation; it is often used in close proximity with digital logic, microcontrollers, microprocessors, and digital signal processors. The more digital logic present in the design and the higher the switching speed, the more difficult it is to achieve good performance from the converter.

Because of the single ground pin of the DACx311, all return currents, including digital and analog return currents, must flow through the GND pin. Ideally, GND is connected directly to an analog ground plane. This plane should be separate from the ground connection for the digital components until they are connected at the power entry point of the system. The power applied to AV_{DD} should be well-regulated and low-noise. Switching power supplies and dc/dc converters often have high-frequency glitches or spikes riding on the output voltage. In addition, digital components can create similar high-frequency spikes as the internal logic switches state. This noise can easily couple into the DAC output voltage through various paths between the power connections and analog output. This condition is particularly true for the DACx311, as the power supply is also the reference voltage for the DAC.

As with the GND connection, AV_{DD} should be connected to a +5V power supply plane or trace that is separate from the connection for digital logic until they are connected at the power entry point. In addition, the 1µF to 10µF and 0.1µF bypass capacitors are strongly recommended. In some situations, additional bypassing may be required, such as a 100µF electrolytic capacitor or even a *Pi* filter made up of inductors and capacitors—all designed to essentially low-pass filter the +5V supply, removing the high-frequency noise.



PARAMETER DEFINITIONS

With the increased complexity of many different specifications listed in product data sheets, this section summarizes selected specifications related to digital-to-analog converters.

STATIC PERFORMANCE

Static performance parameters are specifications such as differential nonlinearity (DNL) or integral nonlinearity (INL). These are dc specifications and provide information on the accuracy of the DAC. They are most important in applications where the signal changes slowly and accuracy is required.

Resolution

Generally, the DAC resolution can be expressed in different forms. Specifications such as IEC 60748-4 recognize the numerical, analog, and relative resolution. The numerical resolution is defined as the number of digits in the chosen numbering system necessary to express the total number of steps of the transfer characteristic, where a step represents both a digital input code and the corresponding discrete analogue output value. The most commonly-used definition of resolution provided in data sheets is the numerical resolution expressed in bits.

Least Significant Bit (LSB)

The least significant bit (LSB) is defined as the smallest value in a binary coded system. The value of the LSB can be calculated by dividing the full-scale output voltage by 2^n , where *n* is the resolution of the converter.

Most Significant Bit (MSB)

The most significant bit (MSB) is defined as the largest value in a binary coded system. The value of the MSB can be calculated by dividing the full-scale output voltage by 2. Its value is one-half of full-scale.

Relative Accuracy or Integral Nonlinearity (INL)

Relative accuracy or integral nonlinearity (INL) is defined as the maximum deviation between the real transfer function and a straight line passing through the endpoints of the ideal DAC transfer function. INL is measured in LSBs.

Differential Nonlinearity (DNL)

Differential nonlinearity (DNL) is defined as the maximum deviation of the real LSB step from the ideal 1LSB step. Ideally, any two adjacent digital codes correspond to output analog voltages that are exactly one LSB apart. If the DNL is within \pm 1LSB, the DAC is said to be monotonic.

Full-Scale Error

Full-scale error is defined as the deviation of the real full-scale output voltage from the ideal output voltage while the DAC register is loaded with the full-scale code (0xFFFF). Ideally, the output should be V_{DD} – 1LSB. The full-scale error is expressed in percent of full-scale range (%FSR).

Offset Error

Offset error is defined as the difference between actual output voltage and the ideal output voltage in the linear region of the transfer function. This difference is calculated by using a straight line defined by two codes (for example, for 16-bit resolution, codes 485 and 64714). Since the offset error is defined by a straight line, it can have a negative or positve value. Offset error is measured in mV.

Zero-Code Error

Zero-code error is defined as the DAC output voltage, when all '0's are loaded into the DAC register. Zero-scale error is a measure of the difference between actual output voltage and ideal output voltage (0V). It is expressed in mV. It is primarily caused by offsets in the output amplifier.

Gain Error

Gain error is defined as the deviation in the slope of the real DAC transfer characteristic from the ideal transfer function. Gain error is expressed as a percentage of full-scale range (%FSR).

Full-Scale Error Drift

Full-scale error drift is defined as the change in full-scale error with a change in temperature. Full-scale error drift is expressed in units of %FSR/°C.

Offset Error Drift

Offset error drift is defined as the change in offset error with a change in temperature. Offset error drift is expressed in μ V/°C.

Zero-Code Error Drift

Zero-code error drift is defined as the change in zero-code error with a change in temperature. Zero-code error drift is expressed in μ V/°C.

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Gain Temperature Coefficient

The gain temperature coefficient is defined as the change in gain error with changes in temperature. The gain temperature coefficient is expressed in ppm of FSR/°C.

Power-Supply Rejection Ratio (PSRR)

Power-supply rejection ratio (PSRR) is defined as the ratio of change in output voltage to a change in supply voltage for a full-scale output of the DAC. The PSRR of a device indicates how the output of the DAC is affected by changes in the supply voltage. PSRR is measured in decibels (dB).

Monotonicity

Monotonicity is defined as a slope whose sign does not change. If a DAC is monotonic, the output changes in the same direction or remains at least constant for each step increase (or decrease) in the input code.

DYNAMIC PERFORMANCE

Dynamic performance parameters are specifications such as settling time or slew rate, which are important in applications where the signal rapidly changes and/or high frequency signals are present.

Slew Rate

The output slew rate (SR) of an amplifier or other electronic circuit is defined as the maximum rate of change of the output voltage for all possible input signals.

$$SR = \max\left[\left|\frac{\Delta V_{OUT}(t)}{\Delta t}\right|\right]$$
(3)

Where $\Delta V_{OUT}(t)$ is the output produced by the amplifier as a function of time *t*.

Output Voltage Settling Time

Settling time is the total time (including slew time) for the DAC output to settle within an error band around its final value after a change in input. Settling times are specified to within $\pm 0.003\%$ (or whatever value is specified) of full-scale range (FSR).

Code Change/Digital-to-Analog Glitch Energy

Digital-to-analog glitch impulse is the impulse injected into the analog output when the input code in the DAC register changes state. It is normally specified as the area of the glitch in nanovolts-second (nV-s), and is measured when the digital input code is changed by 1LSB at the major carry transition.

Digital Feedthrough

Digital feedthrough is defined as impulse seen at the output of the DAC from the digital inputs of the DAC. It is measured when the DAC output is not updated. It is specified in nV-s, and measured with a full-scale code change on the data bus; that is, from all '0's to all '1's and vice versa.

Channel-to-Channel DC Crosstalk

Channel-to-channel dc crosstalk is defined as the dc change in the output level of one DAC channel in response to a change in the output of another DAC channel. It is measured with a full-scale output change on one DAC channel while monitoring another DAC channel remains at midscale. It is expressed in LSB.

Channel-to-Channel AC Crosstalk

AC crosstalk in a multi-channel DAC is defined as the amount of ac interference experienced on the output of a channel at a frequency (f) (and its harmonics), when the output of an adjacent channel changes its value at the rate of frequency (f). It is measured with one channel output oscillating with a sine wave of 1kHz frequency, while monitoring the amplitude of 1kHz harmonics on an adjacent DAC channel output (kept at zero scale). It is expressed in dB.

Signal-to-Noise Ratio (SNR)

Signal-to-noise ratio (SNR) is defined as the ratio of the root mean-squared (RMS) value of the output signal divided by the RMS values of the sum of all other spectral components below one-half the output frequency, not including harmonics or dc. SNR is measured in dB.

Total Harmonic Distortion (THD)

Total harmonic distortion + noise is defined as the ratio of the RMS values of the harmonics and noise to the value of the fundamental frequency. It is expressed in a percentage of the fundamental frequency amplitude at sampling rate f_S .

Spurious-Free Dynamic Range (SFDR)

Spurious-free dynamic range (SFDR) is the usable dynamic range of a DAC before spurious noise interferes or distorts the fundamental signal. SFDR is the measure of the difference in amplitude between the fundamental and the largest harmonically or non-harmonically related spur from dc to the full Nyquist bandwidth (half the DAC sampling rate, or $f_S/2$). A spur is any frequency bin on a spectrum analyzer, or from a Fourier transform, of the analog output of the DAC. SFDR is specified in decibels relative to the carrier (dBc).



Signal-to-Noise plus Distortion (SINAD)

SINAD includes all the harmonic and outstanding spurious components in the definition of output noise power in addition to quantizing any internal random noise power. SINAD is expressed in dB at a specified input frequency and sampling rate, f_S.

DAC Output Noise Density

Output noise density is defined as internally-generated random noise. Random noise is characterized as a spectral density (nV/\sqrt{Hz}) . It is measured by loading the DAC to midscale and measuring noise at the output.

DAC Output Noise

DAC output noise is defined as any voltage deviation of DAC output from the desired value (within a particular frequency band). It is measured with a DAC channel kept at midscale while filtering the output voltage within a band of 0.1Hz to 10Hz and measuring its amplitude peaks. It is expressed in terms of peak-to-peak voltage (V_{pp}).

Full-Scale Range (FSR)

Full-scale range (FSR) is the difference between the maximum and minimum analog output values that the DAC is specified to provide; typically, the maximum and minimum values are also specified. For an *n*-bit DAC, these values are usually given as the values matching with code 0 and $2^n - 1$.

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
DAC5311IDCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
DAC5311IDCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
DAC5311IDCKT	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
DAC5311IDCKTG4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
DAC6311IDCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
DAC6311IDCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
DAC6311IDCKT	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
DAC6311IDCKTG4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
DAC7311IDCKR	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
DAC7311IDCKRG4	ACTIVE	SC70	DCK	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
DAC7311IDCKT	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
DAC7311IDCKTG4	ACTIVE	SC70	DCK	6	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. **TBD:** The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

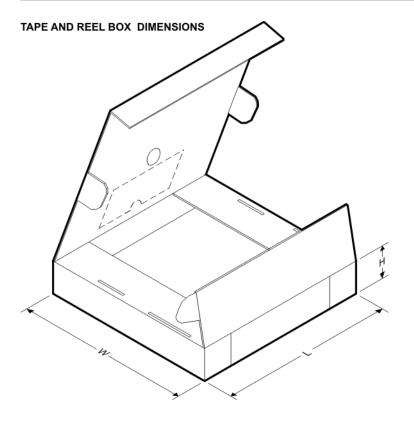


*All dimensions are nominal												
Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DAC5311IDCKR	SC70	DCK	6	3000	177.8	9.7	2.3	2.52	1.2	4.0	8.0	Q3
DAC5311IDCKT	SC70	DCK	6	250	177.8	9.7	2.3	2.52	1.2	4.0	8.0	Q3
DAC6311IDCKR	SC70	DCK	6	3000	177.8	9.7	2.3	2.52	1.2	4.0	8.0	Q3
DAC6311IDCKT	SC70	DCK	6	250	177.8	9.7	2.3	2.52	1.2	4.0	8.0	Q3
DAC7311IDCKR	SC70	DCK	6	3000	177.8	9.7	2.3	2.52	1.2	4.0	8.0	Q3
DAC7311IDCKT	SC70	DCK	6	250	177.8	9.7	2.3	2.52	1.2	4.0	8.0	Q3



PACKAGE MATERIALS INFORMATION

12-Sep-2008



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DAC5311IDCKR	SC70	DCK	6	3000	184.0	184.0	50.0
DAC5311IDCKT	SC70	DCK	6	250	184.0	184.0	50.0
DAC6311IDCKR	SC70	DCK	6	3000	184.0	184.0	50.0
DAC6311IDCKT	SC70	DCK	6	250	184.0	184.0	50.0
DAC7311IDCKR	SC70	DCK	6	3000	184.0	184.0	50.0
DAC7311IDCKT	SC70	DCK	6	250	184.0	184.0	50.0

DCK (R-PDSO-G6)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AB.



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